Eidgenössische Technische Hochschule Zürich

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Structure / properties relationships in doped MgB₂ single crystals

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Pure MgB₂ single crystals at 5K



298K Investigation of possible structural changes in MgB_2 single crystals, which are correlated with superconducting properties (T_c = 39 K), measured with STOE IPDS Imaging Plate at 5 K and 298 K.

- No phase transformation down to 5 K
- No additional reflections or splitting

298 K: 189 (18) reflections; R₁ = 0.033, wR = 0.077

Reconstructed images of zero reciprocal space layer (I = 0); Imaging Plate measurements of pure MgB₂ single crystals at 298 K and 5 K with STOE IPDS; Mo K_{at}; 300 s exposure time; $\Delta \phi = 1^{\circ}$; dd = 150 mm.

5 K: 192 (20) reflections; $R_1 = 0.064$, wR = 0.142 (Bad residual due to He inside Si-sample-tube)



Reconstructed images of reciprocal space layers; CCD measurements of the new Mg-Fe-B compound single crystals with SMART CCD; Mo K_{at} ; 60 s exposure time; $\Delta \phi = 0.3^{\circ}$; dd = 30 mm.